

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S3	2	"20040144300".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:13
S4	30944	(gan or gallium near2 nitride) near10 slop\$5 ("0001")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:14
S6	37	(gan or gallium near2 nitride) near10 slop\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:15
S5	1	(gan or gallium near2 nitride) near10 slop\$5 near10 ("0001")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:15
S2	8	(gan or gallium near2 nitride) near10 step near10 substrate near10 inclin\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:20
S8	9	step near10 flow near10 growth same (gallium near2 nitride or gan) same "0001"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:21
S7	68	step near10 flow near10 growth same (gallium near2 nitride or gan)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 12:21
S9	2	in\$1plane near2 carrier near2 concentrat\$6 near10 (variat\$5 or var\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 14:52
S11	194	carrier near2 concentrat\$6 near10 (variat\$5 or var\$4) near10 layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 14:53

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S10	1026	carrier near2 concentrat\$6 near10 (variatio\$5 or variatio\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 14:53
S12	9	carrier near2 concentrat\$6 near10 (variatio\$5 or variatio\$4) near10 plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 15:15
S13	68	step near2 flow near2 grow\$5 and (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 15:16
S14	26	step near2 flow near2 grow\$5 same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 15:23
S15	57	(gan or gallium near2 nitride) near15 off near4 angle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 15:36
S16	21	uniform\$5 near10 concentrat\$6 near16 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/19 15:37
S18	167	(gan or gallium near2 nitride) near10 variation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/20 11:29
S17	1	(gan or gallium near2 nitride) near10 dopant near10 variation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/20 11:29
S19	2	(gan or gallium near2 nitride) near10 variation near10 impur\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/20 11:35
S21	2	"6447604".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/20 11:54

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S20	32	(gan or gallium near2 nitride) near10 uniform\$6 near10 (impur\$6 or dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/20 11:54
S24	487	in\$1plane near10 (variati\$6 or vary\$5) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:38
S23	988	in\$1plane near10 (variati\$6 or vary\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:38
S22	13	in\$1plane near10 (variati\$6 or vary\$5) near10 (dop\$5 or carrier or impurit\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:38
S25	7	in\$1plane near10 (variati\$6 or vary\$5) same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:41
S26	44	(gan or gallium near2 nitride) near15 (dop\$5 or impurit\$6 or carrier) near10 (variati\$5 or vary\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:45
S28	0	(gan or gallium near2 nitride) near15 (dop\$5 or impurit\$6 or carrier) near10 (uniform\$5) and mean near2 value	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:48
S27	70	(gan or gallium near2 nitride) near15 (dop\$5 or impurit\$6 or carrier) near10 (uniform\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:48
S29	9	(gan or gallium near2 nitride) near15 (dop\$5 or impurit\$6 or carrier) near10 (uniform\$5) and mean	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:50
S32	2	(gan or gallium near2 nitride) and (dop\$5 or impurit\$6 or carrier) near16 (uniform\$5) same mean	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:51

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S31	799	(gan or gallium near2 nitride) and (dop\$5 or impurit\$6 or carrier) near16 (uniform\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:51
S30	2	(gan or gallium near2 nitride) and (dop\$5 or impurit\$6 or carrier) near16 (uniform\$5) near16 mean	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 13:51
S33	6	(gan or gallium near2 nitride) and (dop\$5 or impurit\$6 or carrier) near16 (uniform\$5) near16 variation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 14:04
S35	2	"20060019166".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 14:05
S37	31	"lini.sub.0.8co.sub.0.2o.sub.2" near10 electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 14:07
S36	91	"lini.sub.0.8co.sub.0.2o.sub.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 14:07
S34	1	"lini.sub.08co.sub.0.2o.sub.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/27 14:07
S1	1006	(gan or gallium near2 nitride) near10 step near10 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 14:04
L1	43	(gan or gallium near2 nitride) near10 off near10 (orientat\$6 or step)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 15:06
L2	608	(yasuo near2 kitaoka or hisashi near2 minemoto or isao near2 kidoguchi or akihiko near2 ishibashi).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 15:07

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L3	34	2 and slop\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 15:08
L5	55	2 and group near2 nitride	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 15:09
L4	18	2 and in\$1plane	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/28 15:09